NEIFELD IP LAW REFERENCE FORM	NEIFELD REF: HASH0013UPCUUS1	APPLICATION NO: Divisional of 99/859,732
LIST OF REFERENCES CITED BY THE APPLICANT (Rev: \$/14/2003)	FIRST NAMED INVENTOR: KAWASAKI	10/765901
(1	FILING DATE: herewith	GROUP ART UNIT:

LISTING OF UNITED STATES PATENTS

EXAMINER INITIALS	REFERENCE NUMBER (U SERIES)	PATENT NUMBER	ISSUE DATE	NAME OF PATENTEE OR APPLICANT	PAGE/LINE AND FIGURE/ELEMENT OF RELEVANT MATERIAL AND/OR IDENTIFICATION OF PRIORITY APPLICATION IN WHICH REFERENCE IS CITED
1)	U-1	4,233,573	11-1980	Grudkowski	
77	U-2	4,582,395	04-1986	Morozumi	
13	U-3	5,532,062	07-1996	Miyazaki, et al.	
1	U-4	5,625,199	01-1997	Baumbach, et al.	
D	U-5	5,744,864	04-1998	Cillessen, et al.	
D	U-6	6,410,162	06-2002	White, et al.	
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Date:	1/3/06		Evominer's C:	gnature:	

LISTING OF FOREIGN AND INTERNATIONAL PATENT DOCUMENTS

EXAMINER INITIALS	REFERENCE NUMBER (F SERIES)	PUBLICATION NUMBER	PUBLICATION DATE	COUNTR Y OR REGION	PAGE/LINE AND FIGURE/ELEMENT OF RELEVANT MATERIAL	ENGLISH LANGUAGE TRANSLATION ATTACHED! (YES OR NO) AND/OR IDENTIFICATION OF PRIORITY APPLICATION IN WHICH REFERENCE IS CITED
D	F-1	JP9-199732	07-1997	JP		English abstract
1	F-2	JP57-132191	08-1982	JP		English abstract
1	F-3	JP63-121886	05-1988	JP		English abstract
1	F-4	JP01-065868	03-1989	JP		
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0	F-6	JP63-121886	05-1988	JP		
0	F-7	JP56-125868	10-1981	J.B		English abstract
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Date:	4/23/06	<u> </u>	Examiner's S	ignature:	25	

LISTING OF NON PATENT LITERATURE

EXAMINER INITIALS	REFERENCE NUMBER (L Scries)	PUBLICATION DATE	INCLUDE IN SEQUENCE: Name of first author (in CAPITAL LETTERS), Title in quotation marks, name of publication, date or publication, page numbers, publisher, city of publication, and country of publication	ENGLISH LANGUAGE TRANSLATION ATTACHED? (YES OR NO) AND/OR OR IDENTIFICATION OF PRIORITY APPLICATION IN WHICH REFERENCE IS CITED
2	LI	09-1997	A.ONODERA, et al., "FERROELCTRIC PROPERTIES IN PIEZOELECTRIC SEMICONDUCTOR Zn1-xMxO (M=Li, Mg)", Jpn. J. Appl. Phys., Vol 36, Part 1, No. 9B, Pages 6008-11, September 1997	
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Ø	L-3	11-1968	BOESEN, et al., "ZnO FIELD-EFFECT TRANSISTOR", Proceedings of the IEEE, Pages 2094-95, November 1968	·
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